

EAST: [10606612.mram.with.cladding.for.write.lines.wsp:1]

FileViewEditToolsWindowHelp

Pending

Active

L1: (11) 10/606612

L2: (21643) writ\$4 adj2 line WBL WWL

L3: (1310852) magnetic\$6

L4: (89562) ferri?magnetic\$8 ferri? adj magnetic\$8

L5: (208) ferri?magnetic\$8 ferri? adj magnetic\$8

L6: (1326783) 3 4 5

L7: (1856) (257/295,42) a27.008).CCLS

L8: (286) 6 near2 2

L9: (22) 7 and 8

L10: (68) 8.clm.

L11: (154321) 6.clm.

L12: (68) 10 and 11

L13: (68) 12 and 8

L14: (8624) 6 adj conduct\$4

L15: (5282309) memory element array matrix

L16: (23321) 6 adj 15

L18: (0) 17 same 2

L19: (0) 17 and 2

L17: (73) 16 near6 14

L20: (13) 17.clm.

L21: (8248) 16.ab.

L22: (38) 17 and 21

L23: (28) 22 not 20

Failed

DBs

USPAT:US PGPLB: EPO: JPO: DERVENT: IBM: TDO

Plurals

Default operator: OR

Highlight all hit terms initially

10/606612

Sept 2004

ASIS termASIS termASIS termASIS termASIS term

U+InventorDocumentIssuePTitleCurrentCurrentXPRetrievalS6P33ImageDocP

1F.Tsang, David US 2004015 20040.1 High density and high programming efficienc 257/293RECORDS US 2004015

Ready

3/1/04